

Supporting Information

Towards Continuous Primary Manufacturing Processes – Particle Design through combined Crystallization and Particle Isolation

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Table S1: Operating parameters of the integrated process (SFC & CVSF).

Parameter	CP-Q1.1	CP-Q1.2	CP-Q2.1	CP-Q2.2
Q_{tot} [mL min ⁻¹]	20	20	40	40
Q_{susp} [mL min ⁻¹]	10	10	20	20
$\epsilon_{L,0}$ [-]	0.5	0.5	0.5	0.5
τ_{SFC} [min]	10	10	5	5
$\vartheta_{SFC,IN}$ [°C]	50	50	50	50
$\vartheta_{SFC,OUT}$ [°C]	30	30	30	30
L_{tubing} [m]	26	26	26	26
$d_{i,tubing}$ [mm]	3.18	3.18	3.18	3.18
$\bar{\kappa}$ [K min ⁻¹]	1.8	1.8	3.6	3.6
W_s [g _{solid} g _{sol}]		0.050		0.056
α [-]		0.210		0.119
n_{screw} [rpm]	2	2	2	2
N_{fil} [-]	1	1	1	1
n_{VP} [hz]	26.4	26.4	26.4	26.4
Δp_{set} [mbar]	400	400	400	400
N_{wash} [-]	2	2	2	2
Q_{wash} [mL min ⁻¹]	25	25	25	25
$\tau_{id,CVSF}$ [min]	15	15	15	15

Table S2: Results of the integrated process (SFC & CVSF)

Parameter		CP-Q1.1	CP-Q1.2	CP-Q2.1	CP-Q2.2
$d_{50,3}$ [μm]	Seeds	215.3	215.3	215.3	215.3
	After SFC	436.3	447.3	416.6	450.8
	After CVSF	387.9	419.3	382.7	423.4
$d_{90,3-10,3}$ [μm]	Seeds	109.2	109.2	109.2	109.2
	After SFC	295.9	312.0	311.8	343.2
	After CVSF	288.9	415.7	296.3	324.2
A_{g0} [-]	Seeds	0.57	0.57	0.57	0.57
	After SFC	0.77	0.73	0.72	0.75
	After CVSF	0.52	0.52	0.60	0.71
$n_{part,tot}$ [-]	Seeds	9051	9051	9051	9051
	After SFC	1440	5698	2780	1856
	After CVSF	2722	1142	13450	6445
Y_{rel} [%]		70.0	67.9	48.5	40.6
RM_{ML} [%]		1.1	2.1	1.93	6.05

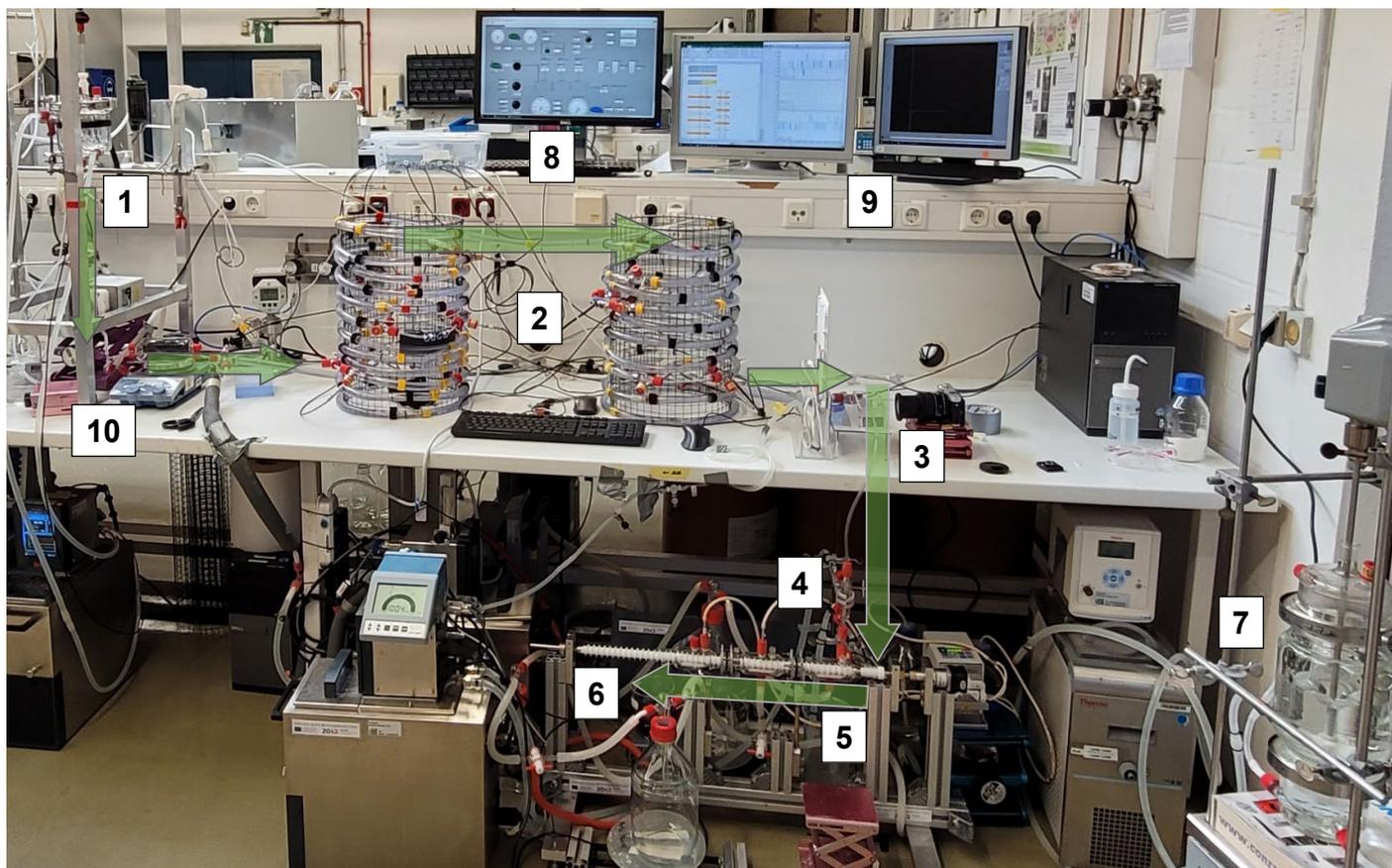


Figure S1: Experimental setup of the integrated process. The material flow is indicated in green arrows. 1: Seed crystal vessel, 2: SFC, 3: connecting element, 4: tube-in-tube heater, 5: CVSF, 6: Filter cake discharge, 7: QICPIC-sample vessel, 8: Control system (CVSF), 9: Control system (SFC)